

# QUICKSWITCH<sup>®</sup> PRODUCTS 2.5V / 3.3V 16-BIT HIGH BANDWIDTH BUS SWITCH

## **FEATURES:**

- N channel FET switches with no parasitic diode to Vcc
  - Isolation under power-off conditions
  - No DC path to Vcc or GND
  - 5V tolerant in OFF and ON state
- 5V tolerant I/Os
- Low Ron 4Ω typical
- · Flat Ron characteristics over operating range
- Rail-to-rail switching 0 5V
- Bidirectional dataflow with near-zero delay: no added ground bounce
- Excellent Ron matching between channels
- Vcc operation: 2.3V to 3.6V
- High bandwidth up to 500MHz
- LVTTL-compatible control Inputs
- · Undershoot Clamp Diodes on all switch and control Inputs
- Low I/O capacitance, 4pF typical
- Available in 40-pin QVSOP package

## **APPLICATIONS:**

- Hot-swapping
- 10/100 Base-T, Ethernet LAN switch
- · Low distortion analog switch
- · Replaces mechanical relay
- ATM 25/155 switching

## FUNCTIONAL BLOCK DIAGRAM

### **OE**1 B0 B1 B2 Вз B4 B5 R6 R<sub>7</sub> A8 A9 A10 A11 A12 A13 A14 A15 $\overline{OF}_{2}$ R8 B9 B10 B11 B12 B13 B14 B15

1

A0 A1

A2 A3

### INDUSTRIAL TEMPERATURE RANGE

## **DESCRIPTION:**

The QS32XVH245 HotSwitch is a high bandwidth, 16-bit bus switch. The QS32XVH245 has very low ON resistance, resulting in under 250ps propagation delay through the switch. The switches can be turned ON under the control of the LVTTL-compatible Output Enable (OEx) signal for bidirectional data flow with no added delay or ground bounce. In the ON state, the switches can pass signals up to 5V. In the OFF state, the switches offer very high impedence at the terminals.

The combination of near-zero propagation delay, high OFF impedance, and over-voltage tolerance makes the QS32XVH245 ideal for high performance communications applications.

The QS32XVH245 is characterized for operation from -40°C to +85°C.5°C.

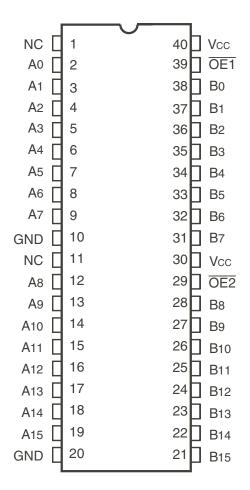
A6

A7

A5

**A**4

### **PIN CONFIGURATION**



#### QVSOP TOP VIEW

#### **INDUSTRIAL TEMPERATURE RANGE**

## ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

Symbol	Description	Max	Unit
VTERM <sup>(2)</sup>	SupplyVoltage to Ground	-0.5 to +4.6	V
VTERM <sup>(3)</sup>	DC Switch Voltage Vs	-0.5 to +5.5	V
VTERM <sup>(3)</sup>	DC Input Voltage VIN	–0.5 to +5.5	V
VAC	AC Input Voltage (pulse width ≤20ns)	-3	V
Ιουτ	DC Output Current (max. sink current/pin)	120	mA
Tstg	Storage Temperature	-65 to +150	°C

NOTES:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

2. Vcc terminals.

3. All terminals except  $\mathsf{Vcc}$  .

### CAPACITANCE (TA = +25°C, F = 1MHz, VIN = 0V, VOUT =

0 <b>S∕ymbol</b>	Parameter <sup>(1)</sup>	Тур.	Max.	Unit
CIN	Control Inputs	3	5	pF
CI/O	Quickswitch Channels (Switch OFF)	4	6	pF
CI/O	Quickswitch Channels (Switch ON)	8	12	pF

NOTE:

1. This parameter is guaranteed but not production tested.

### **PIN DESCRIPTION**

Pin Names	I/O	Description
OEx	I	Output Enable
Ax	I/O	Bus A
Bx	I/O	Bus B

### **FUNCTION TABLE**<sup>(1)</sup>

OEx	Function
Н	Disconnect
L	Connect (Ax = Bx)

NOTE:

1. H = HIGH Voltage Level

L = LOW Voltage Level

## DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

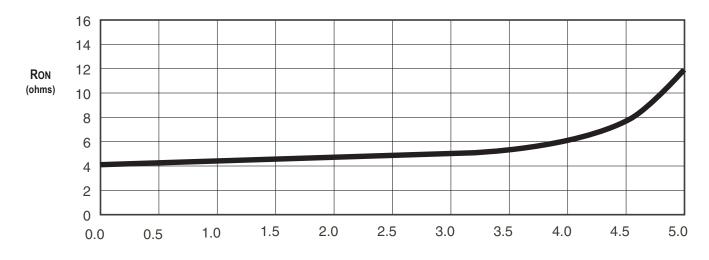
Following Conditions Apply Unless Otherwise Specified: Industrial: TA =  $-40^{\circ}$ C to  $+85^{\circ}$ C, Vcc =  $3.3V \pm 0.3V$ 

Symbol	Parameter	Test C	Conditions		Min.	Typ. <sup>(1)</sup>	Max.	Unit
Vih	Input HIGH Voltage	Guaranteed Logic HIGH	Vcc = 2.3V to 2.7	V	1.7	_	_	V
		for Control Inputs	Vcc = 2.7V to 3.6	SV V	2	—	—	
VIL	Input LOW Voltage	Guaranteed Logic LOW	Vcc = 2.3V to 2.7	'V	—	—	0.7	V
		for Control Inputs	Vcc = 2.7V to 3.6	SV	—	—	0.8	]
lin	Input Leakage Current (Control Inputs)	$0V \le VIN \le VCC$		—	—	±1	μA	
loz	Off-State Current (Hi-Z)	$0V \le V_{OUT} \le 5V$ , Switches OFF		—	—	±1	μA	
IOFF	Data Input/Output Power Off Leakage	VIN or VOUT 0V to 5V, VCC = 0V		—	—	±1	μA	
		Vcc = 2.3V	VIN = 0V	Ion = 30mA	—	6	8	
Ron	Switch ON Resistance	Typical at Vcc = 2.5V	VIN = 1.7V	Ion = 15mA	_	7	9	Ω
		Vcc = 3V	VIN = 0V	Ion = 30mA	_	4	6	
			VIN = 2.4V	Ion = 15mA	_	5	8	

NOTE:

1. Typical values are at Vcc = 3.3V and TA = 25°C.

## TYPICAL ON RESISTANCE vs VIN AT Vcc = 3.3V



VIN (Volts)

## **POWER SUPPLY CHARACTERISTICS**

Symbol	Parameter	Test Conditions <sup>(1)</sup>	Min.	Тур.	Max.	Unit
lccq	Quiescent Power Supply Current	Vcc = Max., VIN = GND or Vcc, f = 0		4	8	mA
ΔICC	Power Supply Current (2.3) per Input HIGH	Vcc = Max., VIN = 3V, f = 0 per Control Input	-	_	30	μA
ICCD	Dynamic Power Supply Current per Output	Vcc = 3.3V, A and B Pins Open, Control Inputs	See Typical	ICCD vs Enab	le Frequency	graph below
	Enable Control Input <sup>(4)</sup>	Toggling @ 50% Duty Cycle				

NOTES:

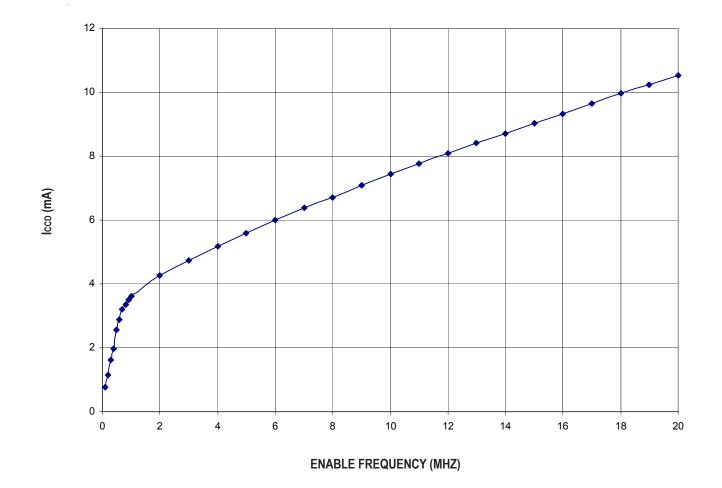
1. For conditions shown as Min. or Max., use the appropriate values specified under DC Electrical Characteristics.

2. Per input driven at the specified level. A and B pins do not contribute to  $\Delta$ Icc.

3. This parameter is guaranteed but not tested.

4. This parameter represents the current required to switch internal capacitance at the specified frequency. The A and B inputs do not contribute to the Dynamic Power Supply Current. This parameter is guaranteed but not production tested.

## TYPICAL ICCD vs ENABLE FREQUENCY CURVE AT VCC = 3.3V



# SWITCHING CHARACTERISTICS OVER OPERATING RANGE

T<sub>A</sub> = -40°C to +85°C

		$Vcc = 2.5 \pm 0.2 V^{(1)}$		$Vcc = 3.3 \pm 0.3 V^{(1)}$		
Symbol	Parameter	Min. <sup>(4)</sup>	Max.	Min. <sup>(4)</sup>	Max.	Unit
<b>t</b> PLH	Data Propagation Delay <sup>(2,3)</sup>		0.2	—	0.2	ns
<b>t</b> PHL	Ax to/from Bx					
tPZL	Switch Turn-On Delay	1.5	8	1.5	7	ns
tРZH	OEx to Ax/Bx					
tPLZ	Switch Turn-Off Delay	1.5	7	1.5	6.5	ns
<b>t</b> PHZ	OEx to Ax/Bx					
fOEx	Operating Frequency - Enable <sup>(2,5)</sup>		10	—	20	MHz

#### NOTES:

1. See Test Conditions under TEST CIRCUITS AND WAVEFORMS.

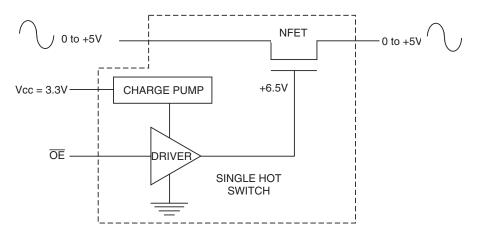
2. This parameter is guaranteed but not production tested.

3. The bus switch contributes no propagation delay other than the RC delay of the ON resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.2ns at C<sub>L</sub> = 50pF. Since this time constant is much smaller than the rise and fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

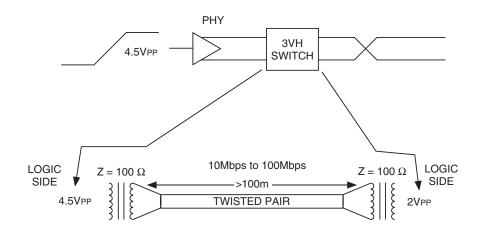
4. Minimums are guaranteed but not production tested.

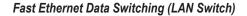
5. Maximum toggle frequency for  $\overline{OEx}$  control input (pass voltage > Vcc, VIN = 5V, RLOAD  $\ge 1M\Omega$ , no CLOAD).

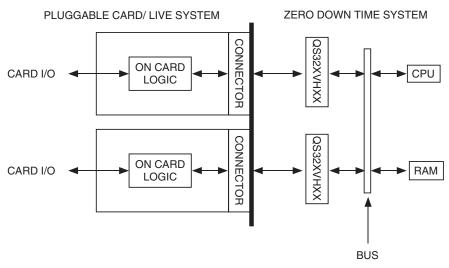
## SOME APPLICATIONS FOR HOTSWITCH PRODUCTS



Rail-to-Rail Switching





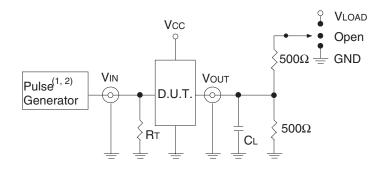


Hot-Swapping

## **TEST CIRCUITS AND WAVEFORMS**

## **TEST CONDITIONS**

Symbol	$Vcc^{(1)}= 3.3V \pm 0.3V$	$Vcc^{(2)} = 2.5V \pm 0.2V$	Unit
Vload	6	2 x Vcc	V
Vih	3	Vcc	V
Vt	1.5	Vcc/2	V
Vlz	300	150	mV
Vнz	300	150	mV
CL	50	30	pF



Test Circuits for All Outputs

#### **DEFINITIONS:**

CL = Load capacitance: includes jig and probe capacitance.

 $\mathsf{R} \mathsf{T} = \mathsf{Termination}$  resistance: should be equal to  $\mathsf{Z} \mathsf{O} \mathsf{U} \mathsf{T}$  of the Pulse Generator.

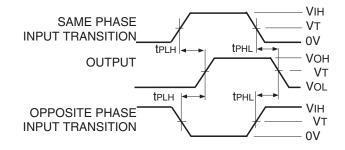
#### NOTES:

1. Pulse Generator for All Pulses: Rate  $\leq$  10MHz; tF  $\leq$  2.5ns; tR  $\leq$  2.5ns.

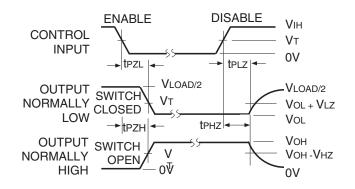
2. Pulse Generator for All Pulses: Rate  $\leq$  10MHz; tF  $\leq$  2ns; tR  $\leq$  2ns.

# **SWITCH POSITION**

Test	Switch
tplz/tpzl	Vload
tphz/tpzh	GND
tPD	Open



### **Propagation Delay**

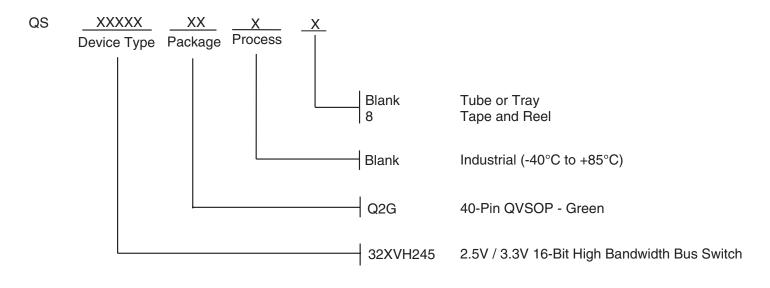


### NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

Enable and Disable Times

### **ORDERING INFORMATION**



## **Datasheet Document History**

09/01/08	Pg. 4, 8	Revise ICCQ Typ. and Max. Remove non green package version and updated the ordering
		information by removing the "IDT" notation.
06/14/11	Pg. 8	Updated ordering information to include tube or tray and tape & reel.

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